



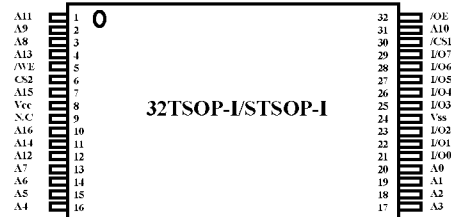
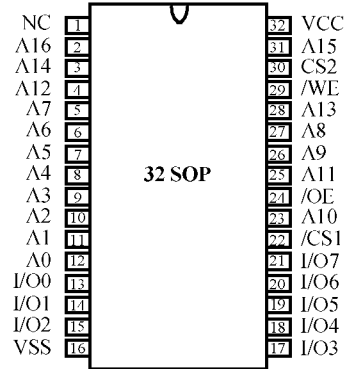
**Description**

The GM76FV8128 / GM76FU8128 / GM76FS8128 / GM76FR8128 is a 1,048,576 bits static random access memory organized as 131,072 words by 8 bits. Using a 0.35 $\mu$ m advanced Full CMOS technology and it provides high speed operation with minimum cycle time of 70/85ns. The device is placed in a low power standby mode with /CS1 high or CS2 low and the output enable (/OE) allows fast memory access. Thus it is suitable for high speed and low super power applications, especially where battery back-up is required.

**Features**

- Fast Speed : 70/85ns
- Power Supply /Speed
  - GM76FV8128 : 3.3V  $\pm$  0.3V / 70/85ns
  - GM76FU8128 : 3.0V  $\pm$  0.3V / 70/85ns
  - GM76FS8128 : 2.5V  $\pm$  0.2V / 100/120ns
  - GM76FR8128 : 2.0V  $\pm$  0.2V / 150/200ns
- Low Power Standby
  - 5 $\mu$ A(LL) / 1 $\mu$ A(SL)
- Completely Static RAM : No Clock or Timing Strobe Required
- Equal Access and Cycle Time
- TTL compatible inputs and outputs
- Capability of Battery Back-up Operation
- Standard 32DIP,SOP and TSOP-I,STSOP-I
- Temperature Range
  - Commercial(0 ~ 70 $^{\circ}$ C)
  - Industrial (-40 ~ 85 $^{\circ}$ C)

**Pin Configuration**

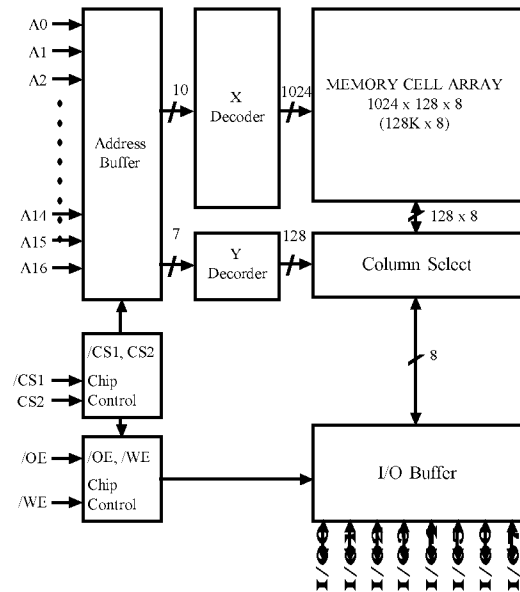


**(Top View)**

**Pin Description**

Pin	Function
A0-A16	Address Inputs
/WE	Write Enable Input
/CS1, CS2	Chip Select Input
/OE	Output Enable Input
I/O0-I/O7	Data Inputs/Outputs
Vcc	Power Supply (1.8V ~3.3V)
Vss	Ground
NC	No Connection

**Block Diagram**



**PRELIMINARY**  
**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

**Absolute Maximum Ratings\***

Symbol	Parameter		Rating	Unit
T <sub>A</sub>	Ambient Temperature under Bias	GM76FV8128 GM76FU8128 GM76FR8128 GM76FS8128	0 ~ 70	°C
		GM76FV8128-I GM76FU8128-I GM76FR8128-I GM76FS8128-I	-40 ~ 85	°C
T <sub>STG</sub>	Storage Temperature		-55 ~ 150	°C
T <sub>SOL</sub>	Soldering Temperature and Time		260, 5 (at lead)	°C, S
V <sub>CC</sub>	Supply Voltage		-0.2 ~ 4.6V	V
V <sub>IN</sub>	Input Voltage		-0.2 ~ 3.9V	V
V <sub>I/O</sub>	Input and Output Voltage		-0.2 ~ 3.9V	V

\*: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

**Recommended DC Operating Conditions ( T<sub>A</sub> = - 40 ~ 85 °C )**

Symbol	Parameter	Product	Min	Typ	Max	Unit
V <sub>CC</sub>	Supply Voltage	GM76FV8128-(I)	3.0	3.3	3.6	V
		GM76FU8128-(I)	2.7	3.0	3.3	
		GM76FS8128-(I)	2.2	2.5	2.8	
		GM76FR8128-(I)	1.8	2.0	2.2	
V <sub>IH</sub>	Input High Voltage	GM76FV8128-(I)	2.2	-	V <sub>CC</sub> + 0.2	V
		GM76FU8128-(I)	2.2			
		GM76FS8128-(I)	2.0			
		GM76FR8128-(I)	1.6			
V <sub>IL</sub>	Input Low Voltage	Family	-0.2*	-	0.4	V

\*Note :V<sub>IL</sub>(min) = -1.5V for ≤ 30ns pulse

**PRELIMINARY**  
**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

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**Truth Table**

/CS1	CS2	/OE	/WE	A0 to A16	DATA I/O	MODE
L	H	L	H	Stable	Output Data	Read
L	H	X	L	Stable	Input Data	Write
L	H	H	H	Stable	Hi-Z	Output Disable
H	X	X	X	-	Hi-Z	Standby
X	L	X	X	-	Hi-Z	

\*Note: X means don't care

**Capacitance** (f = 1MHz, T<sub>A</sub> = 25°C)

Symbol	Parameter	Test Conditions	Min	Max	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>I</sub> = 0V	-	6	pF
C <sub>IO</sub>	Output Capacitance	V <sub>O</sub> = 0V	-	8	pF

\*Note: This parameter is sampled and not 100% tested.

**AC Operating Characteristics**

**Test Conditions** ( T<sub>A</sub> = - 40 ~ 85°C, unless otherwise noted.)

Parameter	Value
Input Pulse Level	0.4 to 2.2V for V <sub>CC</sub> =3.3V,3.0V,2.5V 0.4 to 1.8V for V <sub>CC</sub> =2.0V
Input Rise and Fall Time	5ns
Input and Output Timing Reference Levels	1.5V for V <sub>CC</sub> =3.3V,3.0V 1.1V for V <sub>CC</sub> =2.5V 0.9V for V <sub>CC</sub> =2.0V
Output Load	C <sub>L</sub> = 30 pF + 1TTL Load

**PRELIMINARY**  
**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

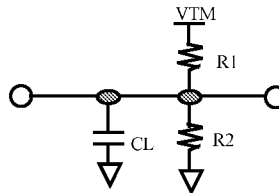
**DC and Operating Characteristics (  $T_A = -40 \sim 85^\circ\text{C}$  )**

Symbol	Parameter	Conditions	Min	*Typ	Max	Unit	
$I_{i(L)}$	Input Leakage Current	$V_{IN} = V_{SS} \text{ to } V_{CC}$	-1	-	1	$\mu\text{A}$	
$I_{o(L)}$	Output Leakage Current	$/CS1 = V_{IH} \text{ or } CS2 = V_{IL}$ $/OE = V_{IH}, V_{SS} \leq V_{OUT} \leq V_{CC}$	-1	-	1	$\mu\text{A}$	
$V_{OH}$	High Level Output Voltage	$I_{OH}$ -1.0mA at $V_{CC}=3.0/3.3\text{V}$ -0.5mA at $V_{CC}=2.5\text{V}$ -0.44mA at $V_{CC}=2.0\text{V}$	2.4 2.0 1.6	-	-	V	
$V_{OL}$	Low Level Output Voltage	$I_{OL}$ 2.1mA at $V_{CC}=3.0/3.3\text{V}$ 0.5mA at $V_{CC}=2.5\text{V}$ 0.33mA at $V_{CC}=2.0\text{V}$	-	-	0.4	V	
$I_{CC}$	Operating Supply Current	$/CS1 = V_{IL} \text{ and } CS2 = V_{IH}$ $V_{IN} = V_{IH}/V_{IL}, I_{OUT} = 0\text{mA}$	-	-	5.0	mA	
$I_{CC1}$	Average Operating Current	$/CS1=V_{IL}, CS2=V_{IH}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OUT} = 0\text{mA}$ tcycle = Min	$V_{CC}=3.0/3.3\text{V}$ $V_{CC}=2.5\text{V}$ $V_{CC}=2.0\text{V}$	-	-	50 30 15	mA
$I_{CC2}$		$/CS1=0.2\text{V}, CS2=V_{CC}-0.2\text{V}$ $V_{IN} = V_{CC} - 0.2\text{V}/0.2\text{V}$ $I_{OUT} = 0\text{mA}$ tcycle = 1 $\mu\text{s}$	-	-	10	mA	
$I_{CCS1}$	Standby Current (TTL)	$/CS1 = V_{IH}$ $CS2 = V_{IL}$	$V_{CC}=3.0/3.3\text{V}$ $V_{CC}=2.5/2.0$	-	-	0.5 0.3	mA
$I_{CCS2}$	Standby Current(CMOS)	$/CS1=V_{CC}-0.2\text{V}$ $CS2=0.2\text{V}$	LL - Version SL - Version	- -	- -	5 1	$\mu\text{A}$

\*Typ. Values are measured at 25 °C

**AC Test Load Conditions.**

- Including scope and jig capacitance
- $R1=3070\Omega$  ,  $R2=3150\Omega$
- $V_{TM}=2.8\text{V}$   $V_{CC}=3.0\text{V}/3.3\text{V}$   
 $V_{TM}=2.3\text{V}$   $V_{CC}=2.5\text{V}$   
 $V_{TM}=1.8\text{V}$   $V_{CC}=2.0\text{V}$
- $CL=30\text{pF} + 1\text{TTL}$   
5pF + 1TTL( For tCLZ1,tCLZ2,tOLZ,tCHZ1  
tCHZ2,tOHZ,tWHZ,tOW)



**PRELIMINARY**

**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

**AC Operating Characteristics** ( $V_{CC} = 3.3V \pm 0.3V$ ,  $3.3V \pm 0.3V$ ,  $T_A = -40 \sim 85^\circ C$ )

**Read Cycle**

Symbol	Parameter	GM76FV8128-70 GM76FU8128-70		GM76FV8128-85 GM76FU8128-85		Unit
		Min	Max	Min	Max	
t <sub>RC</sub>	Read Cycle Time	70	-	85	-	ns
t <sub>AA</sub>	Address Access Time	-	70	-	85	ns
t <sub>ACS1</sub>	Chip Select 1 Access Time	-	70	-	85	ns
t <sub>ACS2</sub>	Chip Select 2 Access Time	-	70	-	85	ns
t <sub>OE</sub>	Output Enable Access Time	-	35	-	45	ns
t <sub>CLZ1</sub>	Chip Select 1 Output Setup Time	5	-	10	-	ns
t <sub>CI1Z1</sub>	Chip Select 1 Output Floating	-	25	-	30	ns
t <sub>CLZ2</sub>	Chip Select 2 Output Setup Time	5	-	10	-	ns
t <sub>CI2Z2</sub>	Chip Select 2 Output Floating	-	25	-	30	ns
t <sub>OLZ</sub>	Output Enable Output Setup Time	0	-	0	-	ns
t <sub>O1Z</sub>	Output Enable Output Floating	-	25	-	30	ns
t <sub>O11</sub>	Output Hold Time	10	-	10	-	ns

**Write Cycle**

Symbol	Parameter	GM76FV8128-70 GM76FU8128-70		GM76FV8128-85 GM76FU8128-85		Unit
		Min	Max	Min	Max	
t <sub>wc</sub>	Write Cycle Time	70	-	85	-	ns
t <sub>cw1</sub>	Chip Select Time 1	65	-	75	-	ns
t <sub>cw2</sub>	Chip Select Time 2	65	-	75	-	ns
t <sub>AW</sub>	Address Enable Time	60	-	70	-	ns
t <sub>AS</sub>	Address Setup Time	0	-	0	-	ns
t <sub>WP</sub>	Write Pulse Width	50	-	60	-	ns
t <sub>WR</sub>	Write Recovery Time	0	-	0	-	ns
t <sub>DW</sub>	Input Data Setup Time	30	-	35	-	ns
t <sub>D11</sub>	Input Data Hold Time	0	-	0	-	ns
t <sub>w1Z</sub>	Write to Output in High-Z	-	25	-	30	ns
t <sub>OW</sub>	Output Active from End of Write	0	-	0	-	ns

**PRELIMINARY**  
**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

**AC Operating Characteristics** ( $V_{CC} = 2.5V \pm 0.2V$ ,  $T_A = -40 \sim 85^\circ C$ )

**Read Cycle**

Symbol	Parameter	GM76FS8128-10		GM76FS8128-12		Unit
		Min	Max	Min	Max	
$t_{RC}$	Read Cycle Time	100	-	120	-	ns
$t_{AA}$	Address Access Time	-	100	-	120	ns
$t_{ACS1}$	Chip Select 1 Access Time	-	100	-	120	ns
$t_{ACS2}$	Chip Select 2 Access Time	-	100	-	120	ns
$t_{OE}$	Output Enable Access Time	-	50	-	60	ns
$t_{CLZ1}$	Chip Select 1 Output Setup Time	10	-	10	-	ns
$t_{CIZ1}$	Chip Select 1 Output Floating	-	35	-	40	ns
$t_{CLZ2}$	Chip Select 2 Output Setup Time	10	-	10	-	ns
$t_{CIZ2}$	Chip Select 2 Output Floating	-	35	-	40	ns
$t_{OLZ}$	Output Enable Output Setup Time	0	-	0	-	ns
$t_{OIZ}$	Output Enable Output Floating	-	35	-	40	ns
$t_{OH}$	Output Hold Time	15	-	15	-	ns

**Write Cycle**

Symbol	Parameter	GM76FS8128-10		GM76FS8128-12		Unit
		Min	Max	Min	Max	
$t_{WC}$	Write Cycle Time	100	-	120	-	ns
$t_{CW1}$	Chip Select Time 1	80	-	100	-	ns
$t_{CW2}$	Chip Select Time 2	80	-	100	-	ns
$t_{AW}$	Address Enable Time	80	-	100	-	ns
$t_{AS}$	Address Setup Time	0	-	0	-	ns
$t_{WP}$	Write Pulse Width	70	-	80	-	ns
$t_{WR}$	Write Recovery Time	0	-	0	-	ns
$t_{DW}$	Input Data Setup Time	40	-	50	-	ns
$t_{DH}$	Input Data Hold Time	0	-	0	-	ns
$t_{WHZ}$	Write to Output in High-Z	-	30	-	35	ns
$t_{OW}$	Output Active from End of Write	5	-	5	-	ns

**PRELIMINARY**  
**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

**AC Operating Characteristics** ( $V_{CC} = 2.0V \pm 0.2V$ ,  $T_A = -40 \sim 85^\circ C$ )

**Read Cycle**

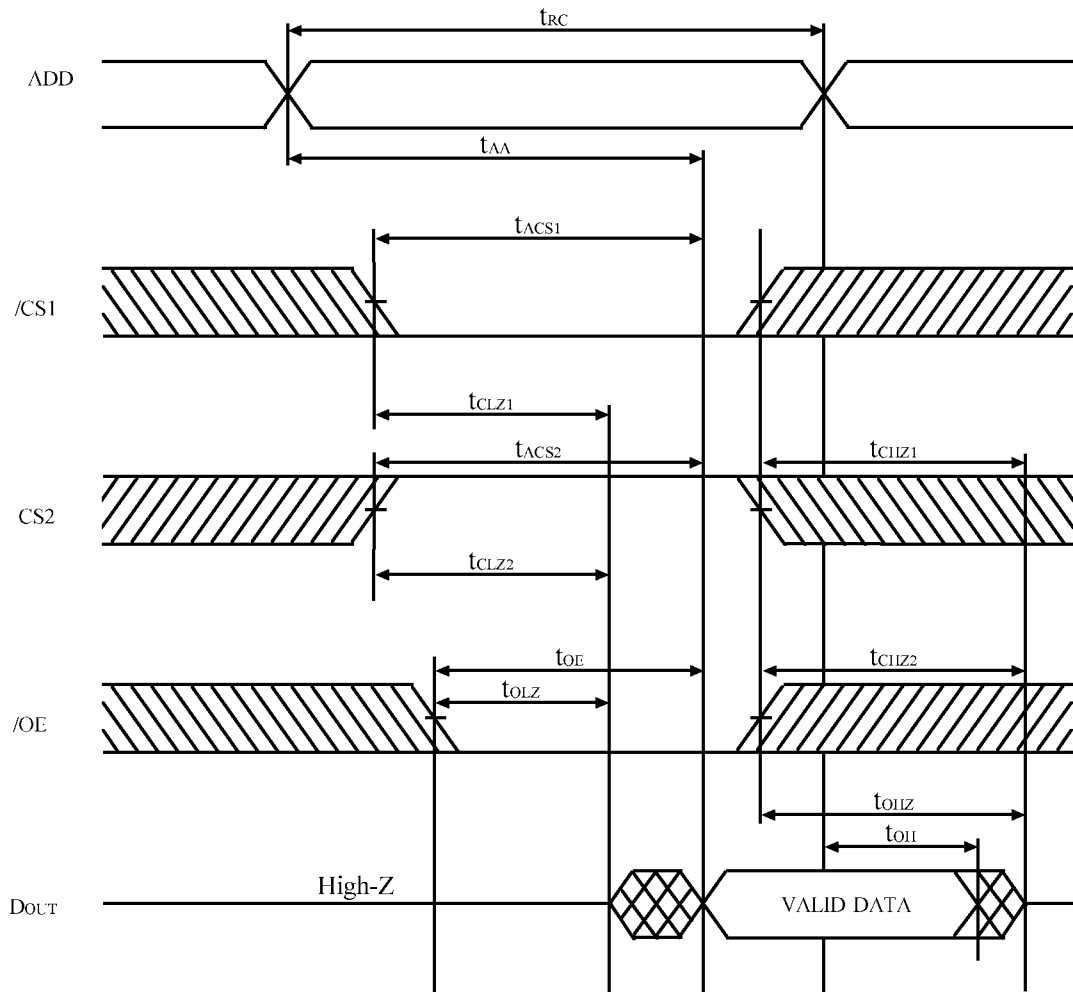
Symbol	Parameter	GM76FR8128-15		GM76FR8128-20		Unit
		Min	Max	Min	Max	
t <sub>RC</sub>	Read Cycle Time	150	-	200	-	ns
t <sub>AA</sub>	Address Access Time	-	150	-	200	ns
t <sub>ACS1</sub>	Chip Select 1 Access Time	-	150	-	200	ns
t <sub>ACS2</sub>	Chip Select 2 Access Time	-	150	-	200	ns
t <sub>OE</sub>	Output Enable Access Time	-	70	-	80	ns
t <sub>CLZ1</sub>	Chip Select 1 Output Setup Time	15	-	15	-	ns
t <sub>CIZ1</sub>	Chip Select 1 Output Floating	-	40	-	45	ns
t <sub>CLZ2</sub>	Chip Select 2 Output Setup Time	15	-	15	-	ns
t <sub>CIZ2</sub>	Chip Select 2 Output Floating	-	40	-	45	ns
t <sub>OLZ</sub>	Output Enable Output Setup Time	0	-	0	-	ns
t <sub>OIZ</sub>	Output Enable Output Floating	-	40	-	45	ns
t <sub>OII</sub>	Output Hold Time	15	-	15	-	ns

**Write Cycle**

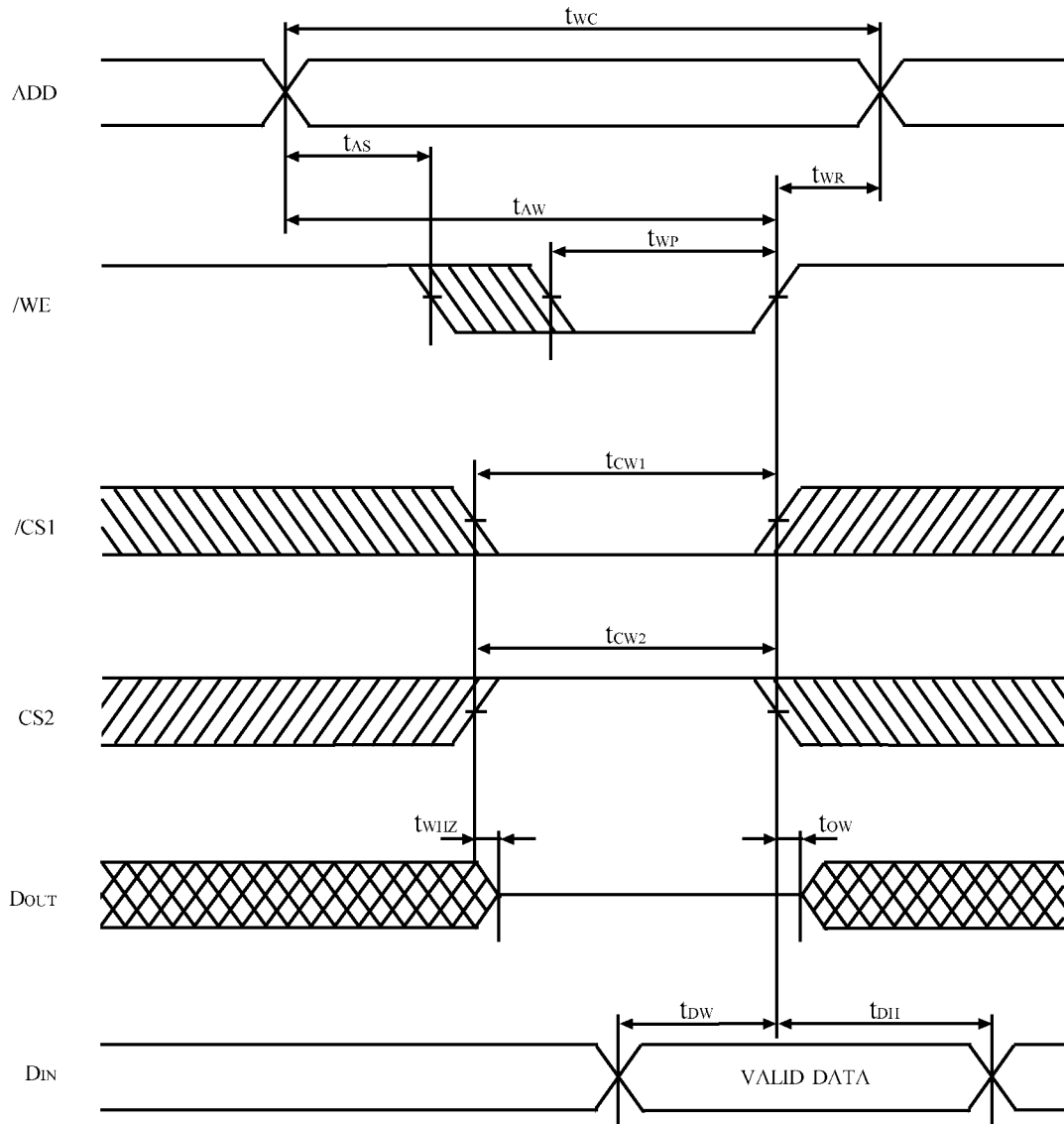
Symbol	Parameter	GM76FR8128-15		GM76FR8128-20		Unit
		Min	Max	Min	Max	
t <sub>wc</sub>	Write Cycle Time	150	-	200	-	ns
t <sub>cw1</sub>	Chip Select Time 1	120	-	150	-	ns
t <sub>cw2</sub>	Chip Select Time 2	120	-	150	-	ns
t <sub>AW</sub>	Address Enable Time	120	-	150	-	ns
t <sub>AS</sub>	Address Setup Time	0	-	0	-	ns
t <sub>wP</sub>	Write Pulse Width	100	-	120	-	ns
t <sub>wR</sub>	Write Recovery Time	0	-	0	-	ns
t <sub>dw</sub>	Input Data Setup Time	60	-	80	-	ns
t <sub>dII</sub>	Input Data Hold Time	0	-	0	-	ns
t <sub>wIIZ</sub>	Write to Output in High-Z	-	35	-	40	ns
t <sub>ow</sub>	Output Active from End of Write	10	-	10	-	ns

**Timing Waveforms**

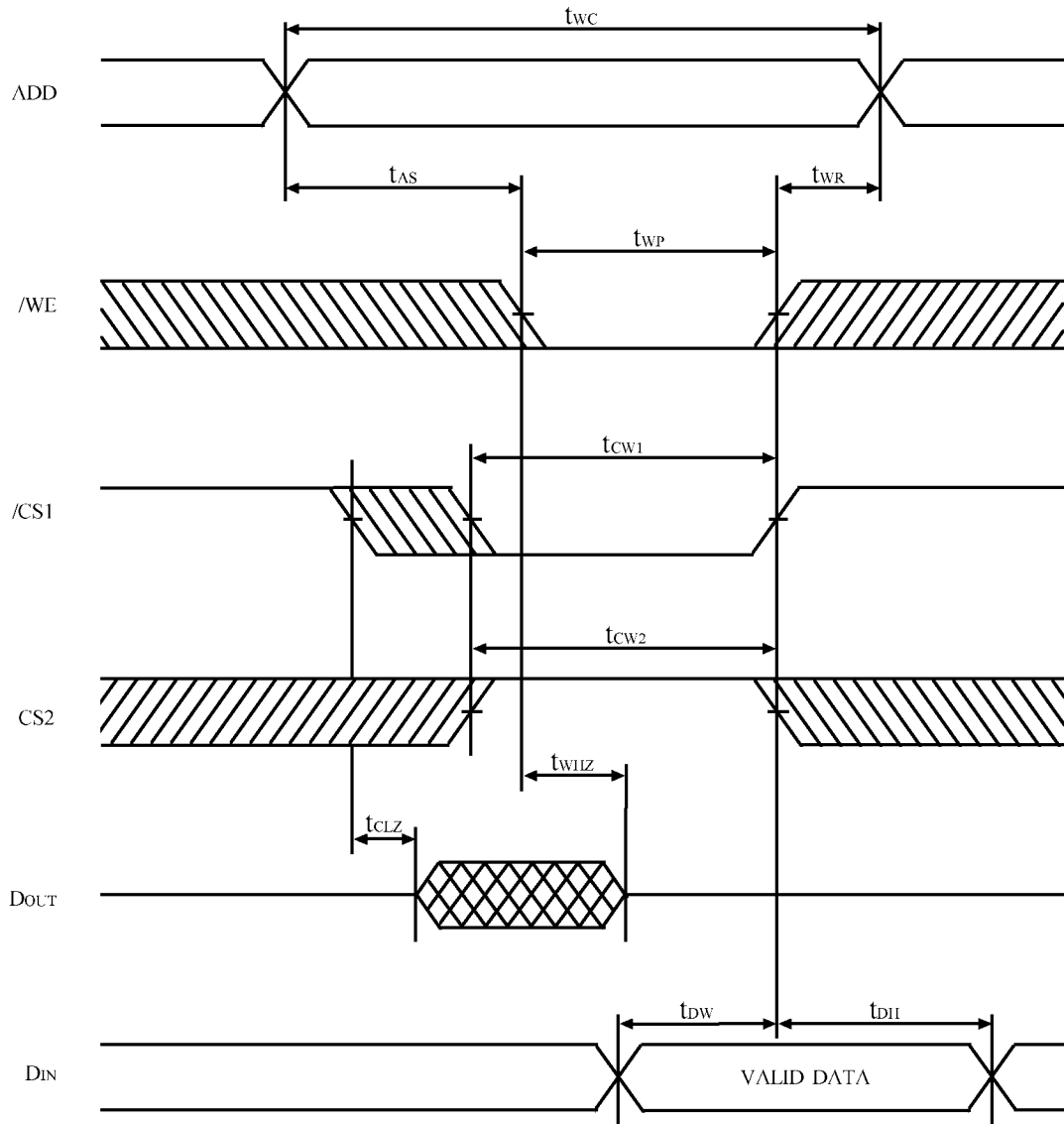
**Read Cycle (Note 1)**



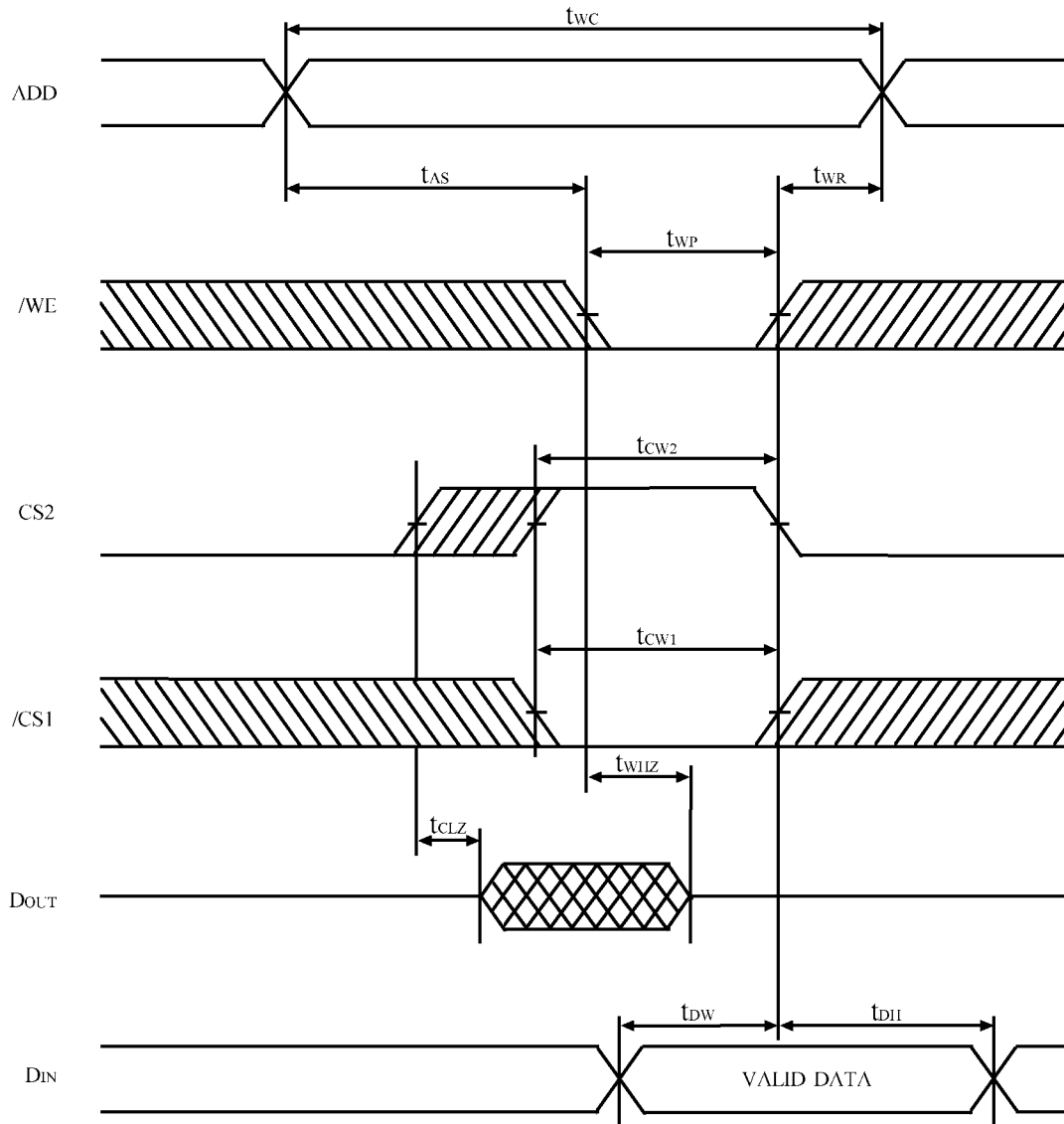
**Write Cycle (1) (/WE Controlled) (Notes 2, 3, 4)**



**Write Cycle (2) (/CS1 Controlled) (Notes 4)**



**Write Cycle (3) (CS2 Controlled) (Notes 4)**



**Notes:**

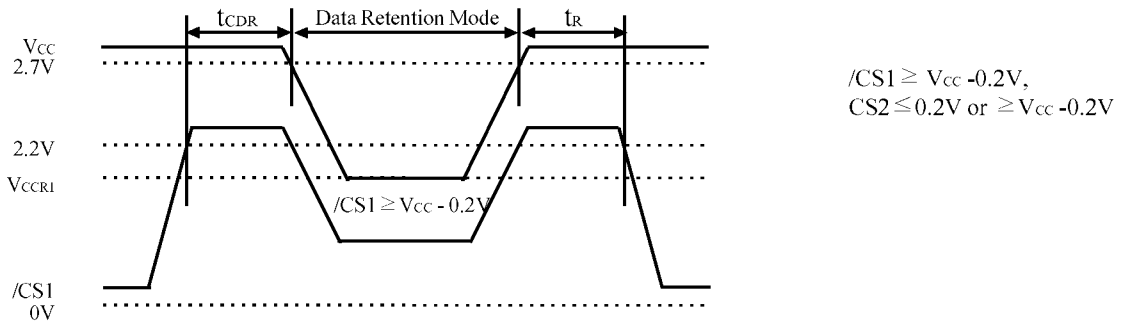
1. /WE is High for Read Cycle.
2. Assuming that /CS1 Low transition or CS2 High transition occurs coincident with or after /WE Low transition. Outputs remain in a high impedance state.
3. Assuming that /CS1 High transition or CS2 Low transition occurs coincident with or prior to /WE High transition. Outputs remain in a high impedance state.
4. Assuming that /OE is high for write cycle. Outputs are in a high impedance state during this period.

**PRELIMINARY**  
**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

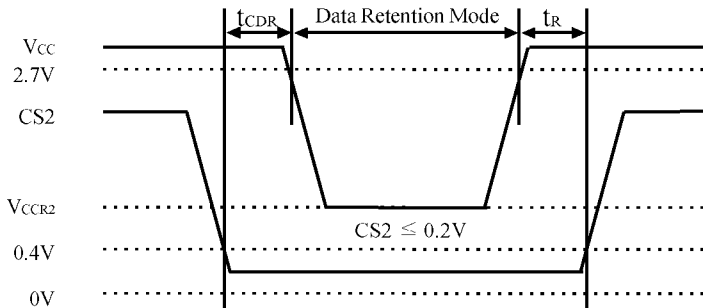
**Data Retention Characteristics**

Symbol	Parameter	Min	Typ	Max	Unit
V <sub>CCR</sub>	Data Retention Supply Voltage	1.5	-	3.6	V
I <sub>CCR</sub>	Data Retention Current				
	LL- Version	-		5	uA
	SL - Version	-		1	
t <sub>CDR</sub>	Chip Select to Data Retention Time	0	-	-	ms
t <sub>r</sub>	Operation Recovery Time	5	-	-	ms

• **Low V<sub>CC</sub> Data Retention Mode: (1) /CS1 Controlled**



• **Low V<sub>CC</sub> Data Retention Mode: (2) CS2 Controlled**



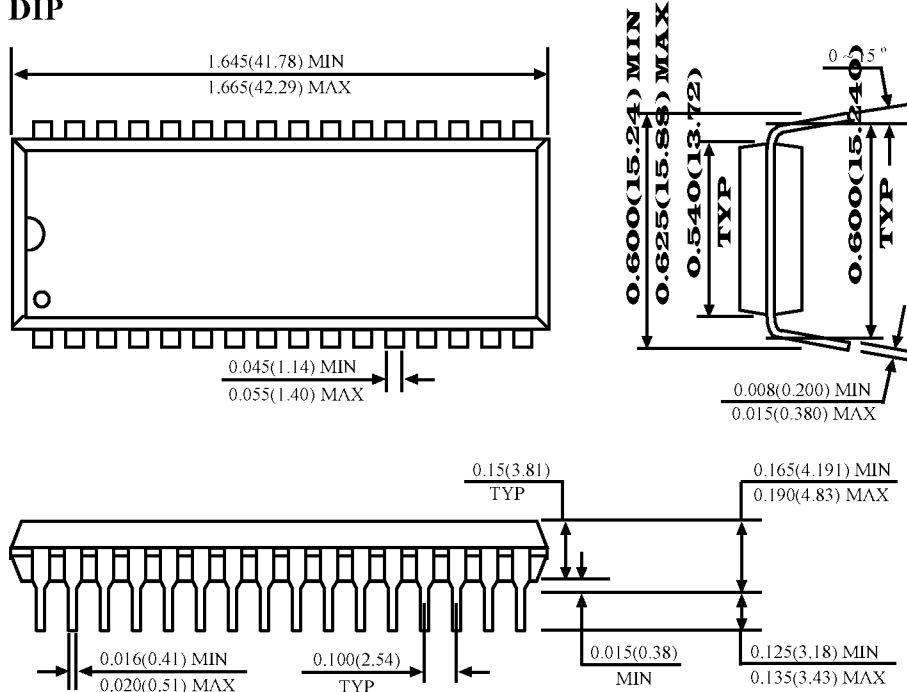
Notes: In Data Retention Mode, CS2 controls the Address, /WE, /CS1, /OE and D<sub>IN</sub> buffer. If CS2 controls data retention mode, V<sub>IN</sub> for these inputs can be in the high impedance state. If /CS1 controls the data retention mode, CS2 must satisfy either CS2 ≥ V<sub>CC</sub> - 0.2V or CS2 ≤ 0.2V. The other input levels (Address, /WE, /OE, I/O) can be in the high impedance state.

**PRELIMINARY**  
**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

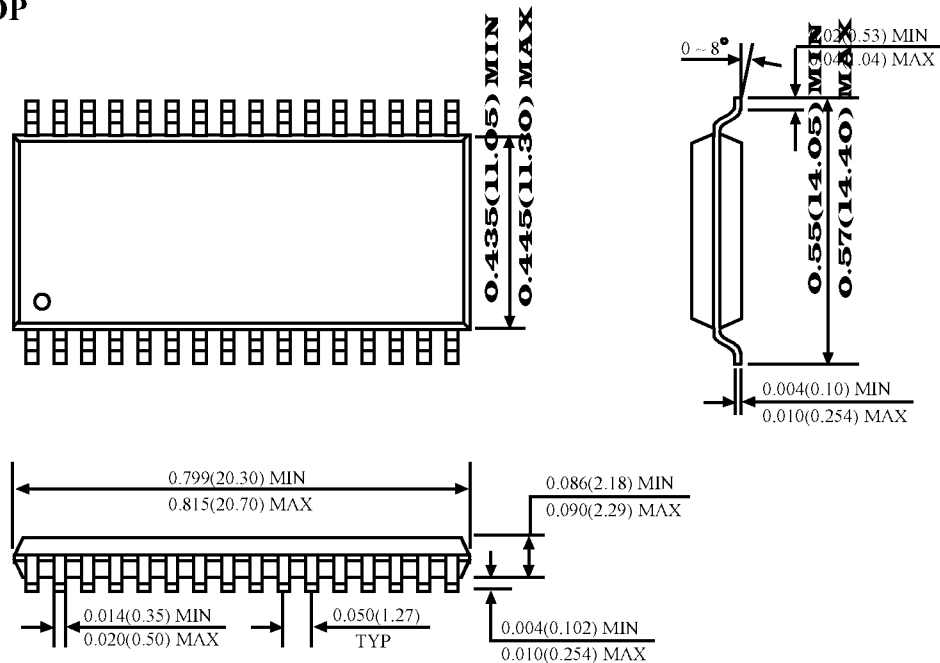
**Package Dimensions**

Unit: Inches (mm)

**32 DIP**

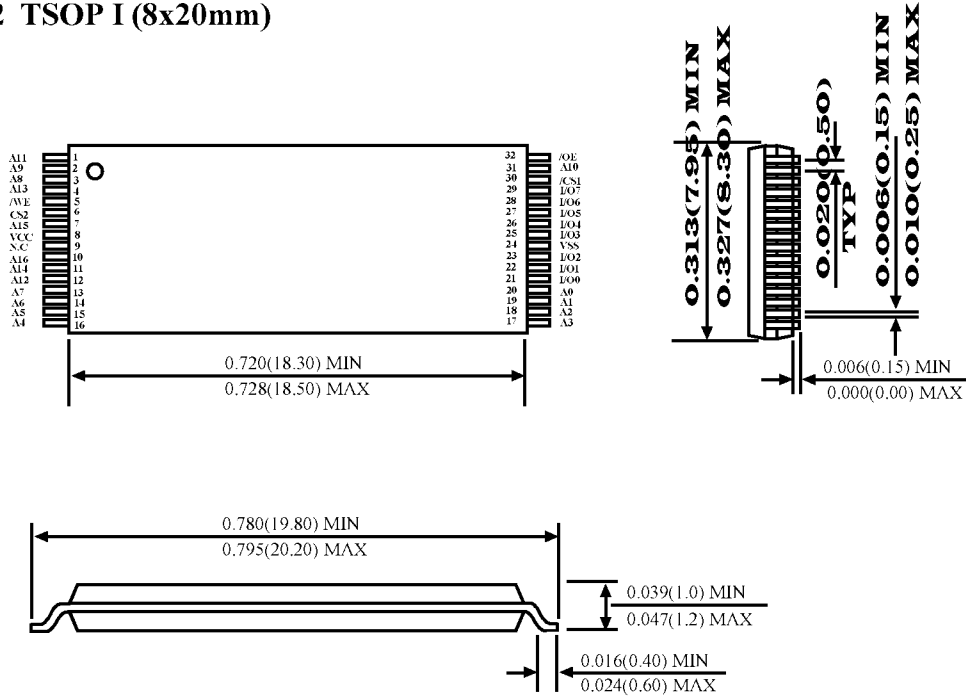


**32 SOP**



**PRELIMINARY**  
**GM76FV8128,GM76FU8128,GM76FS8128,GM76FR8128**

**32 TSOP I (8x20mm)**



**32Small TSOP-I(8x13.4mm)**

